

# FDC6901L Datasheet



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DiGi Electronics Part Number FDC6901L-DG

Manufacturer onsemi

Manufacturer Product Number FDC6901L

Description IC PWR SWITCH P-CH 1:1 SUPERSOT6

Detailed Description Power Switch/Driver 1:1 P-Channel 3A SuperSOT™

-6



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## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
FDC6901L	onsemi
Series:	Product Status:
	Obsolete
Switch Type:	Number of Outputs:
General Purpose	1
Ratio - Input:Output:	Output Configuration:
1:1	
Output Type:	Interface:
P-Channel	On/Off
Voltage - Load:	Voltage - Supply (Vcc/Vdd):
2.7V ~ 6V	
Current - Output (Max):	Rds On (Typ):
3A	105mOhm
Input Type:	Features:
Non-Inverting	Slew Rate Controlled
Fault Protection:	Operating Temperature:
	-55°C ~ 150°C (TJ)
Mounting Type:	Supplier Device Package:
Surface Mount	SuperSOT™-6
Package / Case:	Base Product Number:
SOT-23-6 Thin, TSOT-23-6	FDC6901

## **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.29.0095



February 2008

## FDC6901L Integrated Load Switch

#### **Features**

- Three Programmable Slew Rates
- Reduces Inrush Current
- Minimizes EMI
- Normal Turn-Off Speed
- Low-Power CMOS Operates Over Wide Voltage Range
- High Performance Trench Technology for Extremely low R<sub>DS(ON)</sub>
- RoHS Compliant

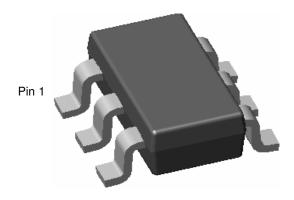
#### **Applications**

- Load switch
- Power management



#### **General Description**

This device is particularly suited for compact power management. In portable electronic equipment where 2.5V to 6V input capability is needed. This load switch integrates a Slew Rate Control Driver that drives a P-Channel Power MOSFET in one tiny SuperSOT<sup>TM</sup>-6 package. The integrated slew rate control driver is specifically designed to control the turn on of the P-Channel MOSFET in order to limit the inrush current in battery switching applications with high capacitance loads. For turn-off, the IC pulls the MOSFET gate up quickly.

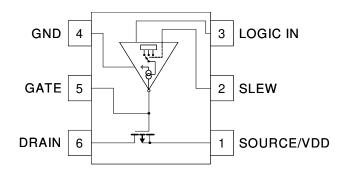


### **Package Marking and Ordering Information**

Device Marking	Device	Reel Size	Tape Width	Quantity
.901	FDC6901L	7"	8mm	3000 units

SuperSOTTM-6

## **Pin Configuration**



## **Absolute Maximum Ratings**

Parameter	Min.	Max.	Unit
Supply Voltage	-0.5	10	V
DC Input Voltage (Logic Inputs)	-0.7	9	V
Power Dissipation			
Storage Junction Temperature	-55	150	∞
Thermal Resistance, Junction to Ambient		180	°C/W
Thermal Resistance, Junction to Case		60	°C/W

### **Recommended Operating Range**

Parameter	Min.	Max.	Unit
Supply Voltage	2.7	6	V
Operating Junction Temperature	-55	150	∞

### **Electrical Characteristics**

T<sub>A</sub> = 25 °C unless otherwise noted

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
Logic Levels		1			I	I	1
Logic High Input Voltage	V <sub>IH</sub>	V <sub>DD</sub> = 2.7V to 6.0V		70% V <sub>DD</sub>			V
Logic Low Input Voltage	V <sub>IL</sub>	V <sub>DD</sub> = 2.7V to 6.0V				25% V <sub>DD</sub>	V
Off Characteristics - Slew Rate Co	ontrol Driver						
Supply Input Breakdown Voltage	BV <sub>DG</sub>	$I_{DG} = 10\mu A, V_{IN} =$	= 0V, V <sub>SLEW</sub> = 0V	9			V
Slew Input Breakdown Voltage	BV <sub>SLEW</sub>	$I_{SLEW} = 10\mu A, V_{IN} = 0V$		9			V
Logic Input Breakdown Voltage	BV <sub>IN</sub>	I <sub>IN</sub> = 10μA, V <sub>SLEW</sub> = 0V		9			V
Supply Input Leakage Current	IR <sub>DG</sub>	$V_{DG} = 8V$ , $V_{IN} = 0V$ , $V_{SLEW} = 0V$				100	nA
Slew Input Leakage Current	IR <sub>SLEW</sub>	$V_{SLEW} = 8V, V_{IN} = 0V$				100	nA
Logic Input Leakage Current	IR <sub>IN</sub>	V <sub>IN</sub> = 8V, V <sub>SLEW</sub> = 0V				100	nA
Off Characteristics - Slew Rate Co	ontrol Driver +	P-Channel MOSF	ET		•		
MOSFET Breakdown Voltage	BV <sub>DSS</sub>	I <sub>D</sub> = -250μA		9			V
MOSFET Leakage Current	I <sub>DSS</sub>	V <sub>R</sub> = 16V				100	nA
On Characteristics - Slew Rate Co	ontrol Driver				•		
			Slew Pin = Open	90			μA
Output/Gate Current $I_G$ $I_D =$	$I_{G}$	$I_{D} = -250 \mu A$	Slew Pin = GND	1			μA
		Slew Pin = V <sub>DD</sub>	10			nA	

## **Electrical Characteristics Cont.**

T<sub>A</sub> = 25 °C unless otherwise noted

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Units
On Characteristics - P-Channel MC	SFET	1				I.	•
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -2$	50µA	-0.6	-1	-1.5	V
Static Drain-Source On Resistance	Р	$V_{GS} = -4.5V, I_D = -$	1.5A		120	145	mΩ
Static Diam-Source On Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -1.2A			170	210	mΩ
On Characteristics - Slew Rate Co	ntrol Driver +	P-Channel MOSFE	Т				
Dropout Voltage	V	$V_{DD} = 6V, V_{IN} = 2.5$	$5V \text{ to } 6V, I_L = 1.5A$		160	300	mV
Diopout voitage	V <sub>DROP</sub>	$V_{DD} = 6V, V_{IN} = 2.5$	$5V \text{ to } 6V, I_L = 1.2A$		130	300	mV
Load Switch On Resistance	D	$V_{DD} = 6V, V_{IN} = 2.5$	$5V \text{ to } 6V, I_L = 1.5A$		105	180	mΩ
Load Switch On Resistance $R_{ON}$ $V_{DD} = 6V$ , $V_{IN} = 2.5V$ to		$5V \text{ to } 6V, I_L = 1.2A$		110	210	mΩ	
Load Current	I <sub>LOAD</sub>	V <sub>GS</sub> = 2.5 V, V <sub>DS</sub> = 6 V		3			Α
$ \textbf{P-Channel Switching Times} \; (\textbf{V}_{\text{SUPF}}$	o <sub>LY</sub> = 5.5V, V <sub>DI</sub>	$_{\rm D}$ = 5.5V, Logic IN =	$5.5V, I_{LOAD} = 1.5A)$				
		Slew Pin	= Open		6.2		μs
Delay On Time	$td_{ON}$		= GND		42		μs
			= V <sub>DD</sub>		115		μs
		Slew Pin	= Open		6.75		μs
V <sub>OUT</sub> Rise Time	$t_R$		= GND		124		μs
			= V <sub>DD</sub>		162		μs
Output Slew Rate		Slew Pin	= Open		600		V/ms
	dv/dt		= GND		41		V/ms
			= V <sub>DD</sub>		24		V/ms

3

### **Typical Characteristics**

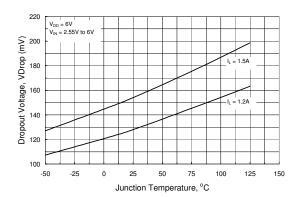


Figure 1. Dropout Voltage vs. Temperature (SLEW = OPEN)

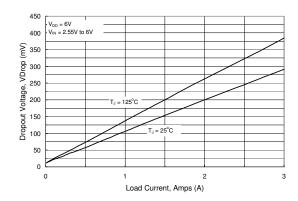


Figure 2. Dropout Voltage vs. Load Current (SLEW = OPEN)

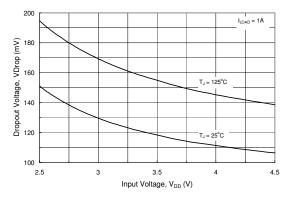


Figure 3. Dropout Voltage vs. Input Voltage (SLEW = OPEN)

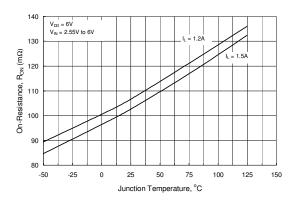


Figure 4. On Resistance vs. Temperature (SLEW = OPEN)

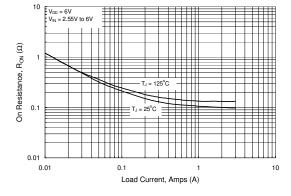


Figure 5. On Resistance vs. Load Current (SLEW = OPEN)

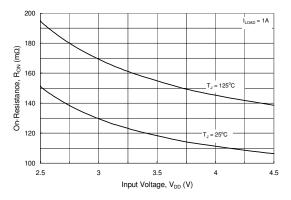


Figure 6. On Resistance vs. Input Voltage (SLEW = OPEN)

## **Typical Characteristics**

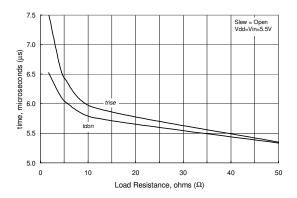


Figure 7. Switching Time vs. Load Resistance (SLEW = OPEN)

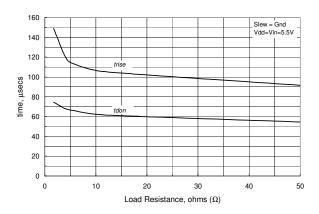


Figure 8. Switching Time vs. Load Resistance (SLEW = GROUND)

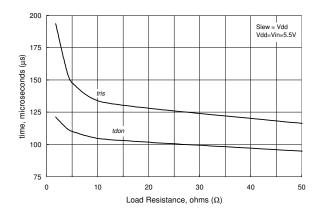


Figure 9. Switching Time vs. Load Resistance  $(SLEW = V_{DD})$ 

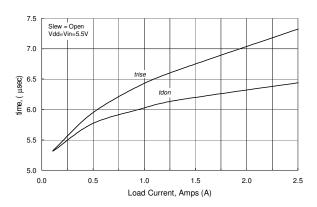


Figure 10. Switching Time vs. Load Current (SLEW = OPEN)

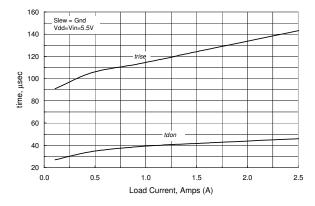


Figure 11. Switching Time vs. Load Current (SLEW = GROUND)

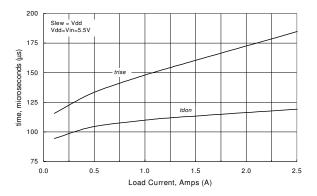
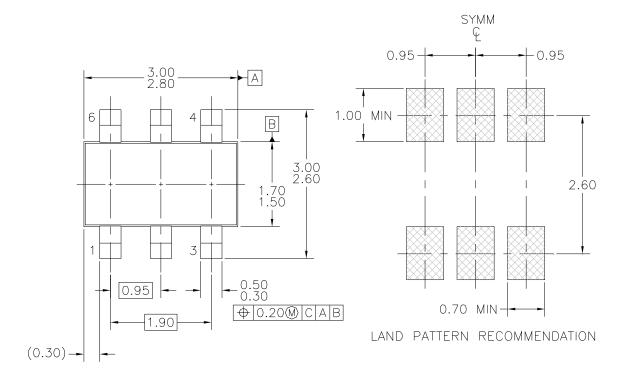
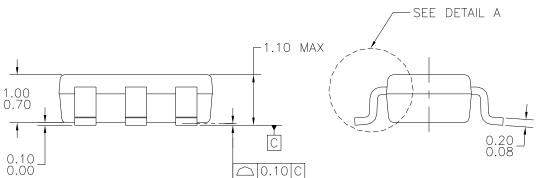
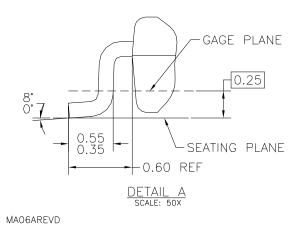


Figure 12. Switching Time vs. Load Current  $(SLEW = V_{DD})$ 

## **Dimensional Outline and Pad Layout**







NOTES: UNLESS OTHERWISE SPECIFIED

- THIS PACKAGE CONFORMS TO JEDEC MO-193. VAR. AA, ISSUE C, DATED JANUARY 2000. ALL DIMENSIONS ARE IN MILLIMETERS.





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